

# RF EXPOSURE Test Report

**Report No.:** MTi221125003-01E2

**Date of issue:** 2023-01-12

**Applicant:** Shenzhen Baseus Technology Co., Ltd.

Product name: Digital Power Bank 420W

Model(s): BPE42B

FCC ID: 2A482-BPE42B

Shenzhen Microtest Co., Ltd. http://www.mtitest.com

Address: 101, No. 7, Zone 2, Xinxing Industrial Park, Fuhai Avenue, Xinhe Community, Fuhai Street, Bao'an District, Shenzhen, Guangdong, China.

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# Instructions

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	TEST RES	ULT CERTIFICATION				
	ILOI KLO	OET CERTIFICATION				
Applicant:	Shenzhen Baseus Technology Co., Ltd.					
Address:		d Floor, Building B, Baseus Intelligence Park, No.2008, Xuegang I,Gangtou Community, Bantian Street, Longgang District, Shenzhen				
Manufacturer:	Shenzhen Baseus Technology Co., Ltd.					
Address:	2nd Floor, Building B, Baseus Intelligence Park, No.2008, Xuegang Rd,Gangtou Community, Bantian Street, Longgang District, Shenzhen					
Factory:	Shenzhen PILOT Technology Co., Ltd					
Address:	A1 Building, No.7 Shankeng Road, Shankeng Industrial Park, Shanxia Community, Pinghu Street, Longgang District, Shenzhen, China					
Product description						
Product name	Digital Power Bank 420W					
Trademark	Baseus					
Model Name	BPE42B					
Series Model	N/A					
Standards	N/A					
Test procedure	KDB 447498 D01 v06					
Date of Test						
Date (s) of performance of tests:		2022-12-20~2023-01-12				
Test Result:		Pass				

Testing Engineer	:	Yanice Xie			
		(Yanice Xie)			
Technical Manager	:	leon chen			
		(Leon Chen)			
Authorized Signatory	:	Tom Xue			
		(Tom Xue)			

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#### 1. Standalone SAR test exclusion considerations

Unless specifically required by the published RF exposure KDB procedures, standalone 1-g head or body and 10-g extremity SAR evaluation for general population exposure conditions, by measurement or numerical simulation, is not required when the corresponding SAR Test Exclusion Threshold condition(s), listed below, is (are) satisfied.

These test exclusion conditions are based on source-based time-averaged maximum conducted output power of the RF channel requiring evaluation, adjusted for tune-up tolerance, and the minimum test separation distance required for the exposure conditions.

The minimum test separation distance defined in 4.1 f) is determined by the smallest distance from the antenna and radiating structures or outer surface of the device, according to the host form factor, exposure conditions and platform requirements, to any part of the body or extremity of a user or bystander.

To qualify for SAR test exclusion, the test separation distances applied must be fully explained and justified, typically in the SAR measurement or SAR analysis report, by the operating configurations and exposure conditions of the transmitter and applicable host platform requirements, according to the required published RF exposure KDB procedures.

When no other RF exposure testing or reporting are required, a statement of justification and compliance must be included in the equipment approval, in lieu of the SAR report, to qualify for SAR test exclusion.

When required, the device specific conditions described in the other published RF exposure KDB procedures must be satisfied before applying these SAR test exclusion provisions.

a) For 100 MHz to 6 GHz and test separation distances ≤ 50 mm, the 1-g and 10-g SAR test exclusion thresholds are determined by the following:

[(max. power of channel, including tune-up tolerance, mW) / (min. test separation distance, mm)]  $\cdot [\sqrt{f(GHz)}] \le 3.0$  for 1-g SAR, and  $\le 7.5$  for 10-g extremity SAR, where

- f<sub>(GHz)</sub> is the RF channel transmit frequency in GHz
- Power and distance are rounded to the nearest mW and mm before calculation
- The result is rounded to one decimal place for comparison
- The values 3.0 and 7.5 are referred to as *numeric thresholds* in step b) below

The test exclusions are applicable only when the minimum test separation distance is  $\leq$  50 mm, and for transmission frequencies between 100 MHz and 6 GHz. When the minimum test separation distance is < 5 mm, a distance of 5 mm according to 4.1 f) is applied to determine SAR test exclusion.

- b) For 100 MHz to 6 GHz and test separation distances > 50 mm, the 1-g and 10-g SAR test exclusion thresholds are determined by the following (also illustrated in Appendix B):
  - 1) {[Power allowed at *numeric threshold* for 50 mm in step a)] + [(test separation distance 50 mm)·(f(MHz)/150)]} mW, for 100 MHz to 1500 MHz
  - 2) {[Power allowed at *numeric threshold* for 50 mm in step a)] + [(test separation distance 50 mm)·10]} mW, for > 1500 MHz and ≤ 6 GHz
- c) For frequencies below 100 MHz, the following may be considered for SAR test exclusion (also illustrated in Appendix C):
  - For test separation distances > 50 mm and < 200 mm, the power threshold at the corresponding test separation distance at 100 MHz in step b) is multiplied by [1 + log(100/f(MHz))]

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- 2) For test separation distances  $\leq$  50 mm, the power threshold determined by the equation in c) 1) for 50 mm and 100 MHz is multiplied by  $\frac{1}{2}$
- 3) SAR measurement procedures are not established below 100 MHz.

When SAR test exclusion cannot be applied, a KDB inquiry is required to determine SAR evaluation requirements for any SAR test results below 100 MHz to be acceptable.

### 2. SAR Test Exclucsion Thresholds

We use 5mm as separation distance to calculated. Bluetooth DTS:

Transmit Frequency	Mode	Measured Power	Tune-up power	Max tune-up	Result	1g SAR
(GHz)	(GHz)	(dBm)	(dBm)	power(dBm)	calculation	
2.402		-4.28	(-4)±1	-3	0.1554	3
2.440	GFSK-1M	-3.54	(-4)±1	-3	0.1566	3
2.480		-2.93	(-3)±1	-2	0.1987	3
2.402		-4.02	(-4)±1	-3	0.1554	3
2.440	GFSK-2M	-3.26	(-4)±1	-3	0.1566	3
2.480		-2.52	(-3)±1	-2	0.1987	3

#### **Conclusion:**

For the max result: 0.1987≤ 3.0 for 1g SAR, No SAR is required.

----END OF REPORT----

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